

vPolyTan™ Solid Tantalum Surface Mount Chip Capacitors, Molded Case, High Performance Polymer Type



FEATURES

- Ultra-low ESR
- Molded case available in 7 case codes
- Terminations:
cases J, P: 100 % tin
case A: 100 % tin or Ni / Pd / Au
cases T, B, V, D: Ni / Pd / Au
- Compatible with “high volume” automatic pick and place equipment
- Moisture sensitivity level 3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

PERFORMANCE / ELECTRICAL CHARACTERISTICS

Operating Temperature: -55 °C to +105 °C

Capacitance Range: 3.3 µF to 680 µF

Capacitance Tolerance: ± 20 %

Voltage Rating: 2.5 V_{DC} to 35 V_{DC}

APPLICATIONS

- Decoupling, smoothing, filtering
- Bulk energy storage in wireless cards
- Infrastructure equipment
- Storage and networking
- Computer motherboards
- Smartphones and tablets

ORDERING INFORMATION

| T55 TYPE | B CASE CODE | 156 CAPACITANCE | M CAPACITANCE TOLERANCE | 6R3 DC VOLTAGE RATING | C TERMINATION / PACKAGING | 0500 ESR |
|-------------|----------------------------------|--|-------------------------------|---|--|---------------------------|
| | See Ratings and Case Codes table | This is expressed in picofarads. The first two digits are the significant figures. The third is the number of zeros to follow. | M = ± 20 % | 2R5 = 2.5 V 004 = 4 V 6R3 = 6.3 V 010 = 10 V 12R = 12.5 V 016 = 16 V 020 = 20 V 025 = 25 V 035 = 35 V | C = lead (Pb)-free solderable coating, 7" reel | Maximum 100 kHz ESR in mΩ |

DIMENSIONS in inches [millimeters]



DIMENSIONS in inches [millimeters]


| CASE CODE | EIA SIZE | L | W | H | l | a |
|-----------|----------|------------------------------|-------------------------------|------------------------------|-------------------------------|------------------------------|
| J | 1608-09 | 0.063 ± 0.004 [1.6 ± 0.1] | 0.031 ± 0.004 [0.8 ± 0.1] | 0.031 ± 0.004 [0.8 ± 0.1] | 0.012 ± 0.006 [0.3 ± 0.15] | 0.024 ± 0.004 [0.6 ± 0.1] |
| P | 2012-12 | 0.080 ± 0.008 [2.0 ± 0.2] | 0.049 ± 0.008 [1.25 ± 0.2] | 0.047 max. [1.2 max.] | 0.020 ± 0.008 [0.5 ± 0.2] | 0.035 ± 0.004 [0.9 ± 0.1] |
| A | 3216-18 | 0.126 ± 0.008 [3.2 ± 0.2] | 0.063 ± 0.008 [1.6 ± 0.2] | 0.063 ± 0.008 [1.6 ± 0.2] | 0.028 ± 0.012 [0.7 ± 0.3] | 0.047 ± 0.008 [1.2 ± 0.2] |
| T | 3528-12 | 0.138 ± 0.008 [3.5 ± 0.2] | 0.110 ± 0.008 [2.8 ± 0.2] | 0.047 max. [1.2 max.] | 0.030 ± 0.012 [0.8 ± 0.3] | 0.087 ± 0.008 [2.2 ± 0.2] |
| B | 3528-21 | 0.138 ± 0.008 [3.5 ± 0.2] | 0.110 ± 0.008 [2.8 ± 0.2] | 0.075 ± 0.008 [1.9 ± 0.2] | 0.030 ± 0.012 [0.8 ± 0.3] | 0.087 ± 0.008 [2.2 ± 0.2] |
| V | 7343-20 | 0.287 ± 0.008 [7.3 ± 0.2] | 0.169 ± 0.012 [4.3 ± 0.3] | 0.075 ± 0.004 [1.9 ± 0.1] | 0.051 ± 0.012 [1.3 ± 0.3] | 0.094 ± 0.008 [2.4 ± 0.2] |
| D | 7343-30 | 0.287 ± 0.008 [7.3 ± 0.2] | 0.169 ± 0.012 [4.3 ± 0.3] | 0.110 ± 0.008 [2.8 ± 0.2] | 0.051 ± 0.012 [1.3 ± 0.3] | 0.094 ± 0.008 [2.4 ± 0.2] |

RATINGS AND CASE CODES

| μF | 2.5 V | 4.0 V | 6.3 V | 10 V | 12.5 V | 16 V | 20 V | 25 V | 35 V |
|-----|-----------|-----------|----------------------|-----------|------------------|------|------|------------------|------------------|
| 3.3 | | | J / P | J / P | | | | | |
| 4.7 | | | J / P / A | P / A | | | | | |
| 6.8 | | | P / A | A | | B | | B | B |
| 10 | | J / P / A | P / A | A | | B | | B | |
| 15 | | P / A | A | A | T ⁽¹⁾ | B | B | B ⁽¹⁾ | |
| 22 | A | A / B | A / T / B | A / T / B | | B | | | D ⁽¹⁾ |
| 33 | A | A / B | A / T / B | A / T / B | | V | | D ⁽¹⁾ | |
| 47 | A | A / T / B | A / T / B | B | | V | | | |
| 68 | A / B | A / T / B | T / B | V | | | | | |
| 100 | A / T / B | A / T / B | A / T / B / V | V / D | | V | | D | |
| 150 | B | B / V | B / V | V | | | | | |
| 220 | B / V | B / V / D | B / V / D | V / D | | | | | |
| 330 | B / V | D / V | V / D | D | | | | | |
| 470 | B / D | D | V ⁽¹⁾ / D | | | | | | |
| 680 | | D | | | | | | | |

Note
⁽¹⁾ In development.

MARKING


| VOLTAGE CODE | | CAPACITANCE CODE | |
|--------------|------|------------------|------|
| V | CODE | CAP, μ F | CODE |
| 2.5 | e | 3.3 | N6 |
| 4 | G | 4.7 | S6 |
| 6.3 | J | 6.8 | W6 |
| 10 | A | 10 | A7 |
| 12.5 | B | 15 | E7 |
| 16 | C | 22 | J7 |
| 20 | D | 33 | N7 |
| 25 | E | 47 | S7 |
| 35 | V | 68 | W7 |
| | | 100 | A8 |
| | | 150 | E8 |
| | | 220 | J8 |
| | | 330 | N8 |
| | | 470 | S8 |
| | | 680 | W8 |



| RATED VOLTAGE | CAPACITANCE | MARKING |
|---------------|-------------|---------|
| 4 | 10 | AG |
| 4 | 15 | EG |
| 6.3 | 3.3 | NJ |
| 6.3 | 4.7 | SJ |
| 6.3 | 6.8 | WJ |
| 6.3 | 10 | AJ |
| 10 | 3.3 | NA |
| 10 | 4.7 | SA |

DATE CODE

| YEAR | MONTH | | | | | | | | | | | |
|------|-------|---|---|---|---|---|---|---|---|----|----|----|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 |
| 2013 | A | B | C | D | E | F | G | H | J | K | L | M |
| 2014 | N | P | Q | R | S | T | U | V | W | X | Y | Z |
| 2015 | a | b | c | d | e | f | g | h | j | k | l | m |
| 2016 | n | p | q | r | s | t | u | v | w | x | y | z |



| STANDARD RATINGS | | | | | | | |
|--------------------------------------|------------------|------------------|------------------------------------|--------------------------------------|--|--|--|
| CAPACITANCE (μ F) | CASE CODE | PART NUMBER | MAX. DCL AT 25 °C (μ A) | MAX. DF AT 25 °C 120 Hz (%) | MAX. ESR AT + 25 °C 100 kHz (m Ω) | MAX. RIPPLE, AT 45 °C 100 kHz I _{RMS} (A) | |
| 2.5 V_{DC} AT +105 °C | | | | | | | |
| 22 | A | T55A226M2R5C0200 | 5.5 | 10 | 200 | 0.75 | |
| 22 | A | T55A226M2R5C0180 | 5.5 | 10 | 180 | 0.79 | |
| 33 | A | T55A336M2R5C0200 | 8.2 | 10 | 200 | 0.75 | |
| 33 | A | T55A336M2R5C0180 | 8.2 | 10 | 180 | 0.79 | |
| 47 | A | T55A476M2R5C0200 | 11.7 | 10 | 200 | 0.75 | |
| 47 | A | T55A476M2R5C0180 | 11.7 | 10 | 180 | 0.79 | |
| 68 | A | T55A686M2R5C0250 | 17.0 | 10 | 250 | 0.67 | |
| 68 | A | T55A686M2R5C0200 | 17.0 | 10 | 200 | 0.75 | |
| 68 | B | T55B686M2R5C0070 | 17.0 | 8 | 70 | 1.36 | |
| 100 | A | T55A107M2R5C0200 | 25.0 | 10 | 200 | 0.75 | |
| 100 | A | T55A107M2R5C0100 | 25.0 | 10 | 100 | 1.07 | |
| 100 | T | T55T107M2R5C0070 | 25.0 | 10 | 70 | 1.22 | |
| 100 | B | T55B107M2R5C0070 | 25.0 | 8 | 70 | 1.36 | |
| 100 | B | T55B107M2R5C0055 | 25.0 | 8 | 55 | 1.53 | |
| 150 | B | T55B157M2R5C0070 | 37.5 | 8 | 70 | 1.36 | |
| 150 | B | T55B157M2R5C0055 | 37.5 | 8 | 55 | 1.53 | |
| 220 | B | T55B227M2R5C0070 | 55.0 | 8 | 70 | 1.36 | |
| 220 | B | T55B227M2R5C0055 | 55.0 | 8 | 55 | 1.53 | |
| 220 | B | T55B227M2R5C0045 | 55.0 | 8 | 45 | 1.69 | |
| 220 | B | T55B227M2R5C0035 | 55.0 | 8 | 35 | 1.93 | |
| 220 | B | T55B227M2R5C0030 | 55.0 | 8 | 30 | 2.08 | |
| 220 | V | T55V227M2R5C0025 | 55.0 | 10 | 25 | 2.73 | |
| 220 | V ⁽¹⁾ | T55V227M2R5C0018 | 55.0 | 10 | 18 | 3.22 | |
| 220 | V ⁽¹⁾ | T55V227M2R5C0015 | 55.0 | 10 | 15 | 3.53 | |
| 330 | B | T55B337M2R5C0070 | 82.5 | 8 | 70 | 1.36 | |
| 330 | B | T55B337M2R5C0045 | 82.5 | 8 | 45 | 1.70 | |
| 330 | B | T55B337M2R5C0035 | 82.5 | 8 | 35 | 1.93 | |
| 330 | B | T55B337M2R5C0025 | 82.5 | 8 | 25 | 2.28 | |
| 330 | V | T55V337M2R5C0040 | 82.5 | 10 | 40 | 2.16 | |
| 330 | V | T55V337M2R5C0025 | 82.5 | 10 | 25 | 2.73 | |
| 330 | V ⁽¹⁾ | T55V337M2R5C0018 | 82.5 | 10 | 18 | 3.22 | |
| 330 | V ⁽¹⁾ | T55V337M2R5C0015 | 82.5 | 10 | 15 | 3.53 | |
| 470 | B | T55B477M2R5C0025 | 117.5 | 8 | 25 | 2.28 | |
| 470 | D | T55D477M2R5C0050 | 117.5 | 10 | 50 | 2.12 | |
| 470 | D | T55D477M2R5C0040 | 117.5 | 10 | 40 | 2.37 | |
| 470 | D | T55D477M2R5C0025 | 117.5 | 10 | 25 | 3.00 | |
| 4 V_{DC} AT +105 °C | | | | | | | |
| 10 | J | T55J106M004C0500 | 10.0 | 10 | 500 | 0.32 | |
| 10 | P | T55P106M004C0500 | 5.0 | 10 | 500 | 0.36 | |
| 10 | P | T55P106M004C0300 | 5.0 | 10 | 300 | 0.46 | |
| 10 | P | T55P106M004C0200 | 5.0 | 10 | 200 | 0.56 | |
| 10 | A | T55A106M004C0500 | 4.0 | 10 | 500 | 0.48 | |
| 10 | A | T55A106M004C0200 | 4.0 | 10 | 200 | 0.76 | |
| 15 | P | T55P156M004C0500 | 10.0 | 10 | 500 | 0.36 | |
| 15 | P | T55P156M004C0200 | 10.0 | 10 | 200 | 0.56 | |
| 15 | A | T55A156M004C0500 | 6.0 | 10 | 500 | 0.48 | |
| 15 | A | T55A156M004C0300 | 6.0 | 10 | 300 | 0.61 | |
| 15 | A | T55A156M004C0200 | 6.0 | 10 | 200 | 0.76 | |

Notes

- Termination code "C": cases J, P: 100 % tin, case A: 100 % tin or Ni/Pd/Au, cases T, B, V, D: Ni/Pd/Au.
- ⁽¹⁾ In development.



| STANDARD RATINGS | | | | | | | |
|------------------------------------|-----------|------------------|------------------------------------|--------------------------------------|--|--|--|
| CAPACITANCE (μ F) | CASE CODE | PART NUMBER | MAX. DCL AT 25 °C (μ A) | MAX. DF AT 25 °C 120 Hz (%) | MAX. ESR AT + 25 °C 100 kHz (m Ω) | MAX. RIPPLE, AT 45 °C 100 kHz I _{RMS} (A) | |
| 4 V_{DC} AT +105 °C | | | | | | | |
| 22 | A | T55A226M004C0500 | 8.8 | 10 | 500 | 0.48 | |
| 22 | A | T55A226M004C0300 | 8.8 | 10 | 300 | 0.61 | |
| 22 | A | T55A226M004C0200 | 8.8 | 10 | 200 | 0.76 | |
| 22 | B | T55B226M004C0150 | 8.8 | 8 | 150 | 0.93 | |
| 22 | B | T55B226M004C0200 | 8.8 | 8 | 200 | 0.81 | |
| 33 | A | T55A336M004C0500 | 13.2 | 10 | 500 | 0.48 | |
| 33 | A | T55A336M004C0300 | 13.2 | 10 | 300 | 0.61 | |
| 33 | A | T55A336M004C0200 | 13.2 | 10 | 200 | 0.76 | |
| 33 | B | T55B336M004C0200 | 13.2 | 8 | 200 | 0.81 | |
| 47 | A | T55A476M004C0500 | 18.8 | 10 | 500 | 0.48 | |
| 47 | A | T55A476M004C0200 | 18.8 | 10 | 200 | 0.76 | |
| 47 | A | T55A476M004C0180 | 18.8 | 10 | 180 | 0.79 | |
| 47 | T | T55T476M004C0200 | 18.8 | 10 | 200 | 0.72 | |
| 47 | T | T55T476M004C0080 | 18.8 | 10 | 80 | 1.15 | |
| 47 | T | T55T476M004C0070 | 18.8 | 10 | 70 | 1.22 | |
| 47 | B | T55B476M004C0150 | 18.8 | 8 | 150 | 0.93 | |
| 47 | B | T55B476M004C0070 | 18.8 | 8 | 70 | 1.36 | |
| 68 | A | T55A686M004C0500 | 27.2 | 10 | 500 | 0.48 | |
| 68 | A | T55A686M004C0250 | 27.2 | 10 | 250 | 0.67 | |
| 68 | A | T55A686M004C0200 | 27.2 | 10 | 200 | 0.76 | |
| 68 | T | T55T686M004C0200 | 27.2 | 10 | 200 | 0.72 | |
| 68 | T | T55T686M004C0180 | 27.2 | 10 | 180 | 0.76 | |
| 68 | T | T55T686M004C0080 | 27.2 | 10 | 80 | 1.15 | |
| 68 | T | T55T686M004C0070 | 27.2 | 10 | 70 | 1.22 | |
| 68 | B | T55B686M004C0150 | 27.2 | 8 | 150 | 0.93 | |
| 68 | B | T55B686M004C0070 | 27.2 | 8 | 70 | 1.36 | |
| 100 | A | T55A107M004C0200 | 40.0 | 10 | 200 | 0.75 | |
| 100 | A | T55A107M004C0100 | 40.0 | 10 | 100 | 1.07 | |
| 100 | T | T55T107M004C0150 | 40.0 | 10 | 150 | 0.84 | |
| 100 | T | T55T107M004C0070 | 40.0 | 10 | 70 | 1.22 | |
| 100 | B | T55B107M004C0070 | 40.0 | 8 | 70 | 1.36 | |
| 100 | B | T55B107M004C0055 | 40.0 | 8 | 55 | 1.53 | |
| 100 | B | T55B107M004C0045 | 40.0 | 8 | 45 | 1.70 | |
| 100 | B | T55B107M004C0040 | 40.0 | 8 | 40 | 1.80 | |
| 100 | B | T55B107M004C0035 | 40.0 | 8 | 35 | 1.92 | |
| 150 | B | T55B157M004C0070 | 60.0 | 8 | 70 | 1.36 | |
| 150 | B | T55B157M004C0055 | 60.0 | 8 | 55 | 1.53 | |
| 150 | B | T55B157M004C0045 | 60.0 | 8 | 45 | 1.69 | |
| 150 | B | T55B157M004C0040 | 60.0 | 8 | 40 | 1.80 | |
| 150 | B | T55B157M004C0035 | 60.0 | 8 | 35 | 1.93 | |
| 150 | V | T55V157M004C0045 | 60.0 | 10 | 45 | 2.03 | |
| 150 | V | T55V157M004C0025 | 60.0 | 10 | 25 | 2.73 | |
| 150 | V | T55V157M004C0015 | 60.0 | 10 | 15 | 3.53 | |
| 220 | B | T55B227M004C0070 | 88.0 | 8 | 70 | 1.36 | |
| 220 | B | T55B227M004C0060 | 88.0 | 8 | 60 | 1.47 | |
| 220 | B | T55B227M004C0055 | 88.0 | 8 | 55 | 1.53 | |
| 220 | B | T55B227M004C0045 | 88.0 | 8 | 45 | 1.70 | |
| 220 | B | T55B227M004C0035 | 88.0 | 8 | 35 | 1.93 | |
| 220 | V | T55V227M004C0055 | 88.0 | 10 | 55 | 1.84 | |
| 220 | V | T55V227M004C0045 | 88.0 | 10 | 45 | 2.03 | |
| 220 | V | T55V227M004C0040 | 88.0 | 10 | 40 | 2.16 | |
| 220 | V | T55V227M004C0035 | 88.0 | 10 | 35 | 2.31 | |
| 220 | V | T55V227M004C0025 | 88.0 | 10 | 25 | 2.73 | |
| 220 | V | T55V227M004C0018 | 88.0 | 10 | 18 | 3.22 | |
| 220 | V | T55V227M004C0015 | 88.0 | 10 | 15 | 3.53 | |
| 220 | D | T55D227M004C0055 | 88.0 | 10 | 55 | 2.02 | |
| 220 | D | T55D227M004C0040 | 88.0 | 10 | 40 | 2.37 | |
| 220 | D | T55D227M004C0025 | 88.0 | 10 | 25 | 3.00 | |

Notes

- Termination code "C": cases J, P: 100 % tin, case A: 100 % tin or Ni/Pd/Au, cases T, B, V, D: Ni/Pd/Au.
- (1) In development.



| STANDARD RATINGS | | | | | | | |
|--------------------------------------|-----------|------------------|------------------------------------|--------------------------------------|--|--|--|
| CAPACITANCE (μ F) | CASE CODE | PART NUMBER | MAX. DCL AT 25 °C (μ A) | MAX. DF AT 25 °C 120 Hz (%) | MAX. ESR AT + 25 °C 100 kHz (m Ω) | MAX. RIPPLE, AT 45 °C 100 kHz I _{RMS} (A) | |
| 4 V_{DC} AT +105 °C | | | | | | | |
| 330 | V | T55V337M004C0050 | 132.0 | 10 | 50 | 1.93 | |
| 330 | V | T55V337M004C0045 | 132.0 | 10 | 45 | 2.03 | |
| 330 | V | T55V337M004C0040 | 132.0 | 10 | 40 | 2.16 | |
| 330 | V | T55V337M004C0025 | 132.0 | 10 | 25 | 2.73 | |
| 330 | V | T55V337M004C0018 | 132.0 | 10 | 18 | 3.22 | |
| 330 | V | T55V337M004C0015 | 132.0 | 10 | 15 | 3.53 | |
| 330 | D | T55D337M004C0050 | 132.0 | 10 | 50 | 2.12 | |
| 330 | D | T55D337M004C0040 | 132.0 | 10 | 40 | 2.37 | |
| 330 | D | T55D337M004C0025 | 132.0 | 10 | 25 | 3.00 | |
| 330 | D | T55D337M004C0015 | 132.0 | 10 | 15 | 3.87 | |
| 470 | D | T55D477M004C0055 | 188.0 | 10 | 55 | 2.02 | |
| 470 | D | T55D477M004C0050 | 188.0 | 10 | 50 | 2.12 | |
| 470 | D | T55D477M004C0040 | 188.0 | 10 | 40 | 2.37 | |
| 470 | D | T55D477M004C0025 | 188.0 | 10 | 25 | 3.00 | |
| 470 | D | T55D477M004C0018 | 188.0 | 10 | 18 | 3.53 | |
| 470 | D | T55D477M004C0015 | 188.0 | 10 | 15 | 3.87 | |
| 680 | D | T55D687M004C0025 | 272.0 | 10 | 25 | 3.00 | |
| 680 | D | T55D687M004C0018 | 272.0 | 10 | 18 | 3.53 | |
| 680 | D | T55D687M004C0015 | 272.0 | 10 | 15 | 3.87 | |
| 6.3 V_{DC} AT +105 °C | | | | | | | |
| 3.3 | J | T55J335M6R3C0500 | 10.0 | 10 | 500 | 0.32 | |
| 3.3 | P | T55P335M6R3C0500 | 5.0 | 10 | 500 | 0.36 | |
| 4.7 | J | T55J475M6R3C0500 | 10.0 | 10 | 500 | 0.32 | |
| 4.7 | P | T55P475M6R3C0500 | 5.0 | 10 | 500 | 0.36 | |
| 4.7 | A | T55A475M6R3C0500 | 3.0 | 10 | 500 | 0.48 | |
| 6.8 | P | T55P685M6R3C0500 | 5.0 | 10 | 500 | 0.36 | |
| 6.8 | A | T55A685M6R3C0500 | 4.2 | 10 | 500 | 0.48 | |
| 10 | P | T55P106M6R3C0500 | 10.0 | 10 | 500 | 0.36 | |
| 10 | P | T55P106M6R3C0200 | 10.0 | 10 | 200 | 0.56 | |
| 10 | A | T55A106M6R3C0500 | 6.3 | 10 | 500 | 0.48 | |
| 10 | A | T55A106M6R3C0300 | 6.3 | 10 | 300 | 0.61 | |
| 10 | A | T55A106M6R3C0200 | 6.3 | 10 | 200 | 0.76 | |
| 15 | A | T55A156M6R3C0500 | 9.4 | 10 | 500 | 0.48 | |
| 15 | A | T55A156M6R3C0300 | 9.4 | 10 | 300 | 0.61 | |
| 15 | A | T55A156M6R3C0200 | 9.4 | 10 | 200 | 0.76 | |
| 22 | A | T55A226M6R3C0500 | 13.8 | 10 | 500 | 0.48 | |
| 22 | A | T55A226M6R3C0300 | 13.8 | 10 | 300 | 0.61 | |
| 22 | A | T55A226M6R3C0200 | 13.8 | 10 | 200 | 0.76 | |
| 22 | T | T55T226M6R3C0150 | 13.8 | 10 | 150 | 0.84 | |
| 22 | T | T55T226M6R3C0070 | 13.8 | 10 | 70 | 1.22 | |
| 22 | B | T55B226M6R3C0150 | 13.8 | 8 | 150 | 0.93 | |
| 33 | A | T55A336M6R3C0500 | 20.7 | 10 | 500 | 0.48 | |
| 33 | A | T55A336M6R3C0200 | 20.7 | 10 | 200 | 0.76 | |
| 33 | A | T55A336M6R3C0180 | 20.7 | 10 | 180 | 0.79 | |
| 33 | T | T55T336M6R3C0200 | 20.7 | 10 | 200 | 0.72 | |
| 33 | T | T55T336M6R3C0150 | 20.7 | 10 | 150 | 0.84 | |
| 33 | T | T55T336M6R3C0070 | 20.7 | 10 | 70 | 1.22 | |
| 33 | B | T55B336M6R3C0200 | 20.7 | 8 | 200 | 0.81 | |
| 33 | B | T55B336M6R3C0150 | 20.7 | 8 | 150 | 0.93 | |
| 33 | B | T55B336M6R3C0080 | 20.7 | 8 | 80 | 1.27 | |
| 33 | B | T55B336M6R3C0070 | 20.7 | 8 | 70 | 1.36 | |
| 33 | B | T55B336M6R3C0040 | 20.7 | 8 | 40 | 1.80 | |

Notes

- Termination code "C": cases J, P: 100 % tin, case A: 100 % tin or Ni/Pd/Au, cases T, B, V, D: Ni/Pd/Au.
- (1) In development.



| STANDARD RATINGS | | | | | | |
|--------------------------------------|------------------|------------------|------------------------------------|--------------------------------------|--|--|
| CAPACITANCE (μ F) | CASE CODE | PART NUMBER | MAX. DCL AT 25 °C (μ A) | MAX. DF AT 25 °C 120 Hz (%) | MAX. ESR AT + 25 °C 100 kHz (m Ω) | MAX. RIPPLE, AT 45 °C 100 kHz I _{RMS} (A) |
| 6.3 V_{DC} AT +105 °C | | | | | | |
| 47 | A | T55A476M6R3C0500 | 29.6 | 10 | 500 | 0.48 |
| 47 | A | T55A476M6R3C0200 | 29.6 | 10 | 200 | 0.76 |
| 47 | A | T55A476M6R3C0180 | 29.6 | 10 | 180 | 0.79 |
| 47 | A | T55A476M6R3C0150 | 29.6 | 10 | 150 | 0.88 |
| 47 | A | T55A476M6R3C0100 | 29.6 | 10 | 100 | 1.07 |
| 47 | A | T55A476M6R3C0070 | 29.6 | 10 | 70 | 1.28 |
| 47 | T | T55T476M6R3C0200 | 29.6 | 10 | 200 | 0.72 |
| 47 | T | T55T476M6R3C0120 | 29.6 | 10 | 120 | 0.93 |
| 47 | T | T55T476M6R3C0080 | 29.6 | 10 | 80 | 1.15 |
| 47 | T | T55T476M6R3C0070 | 29.6 | 10 | 70 | 1.22 |
| 47 | B | T55B476M6R3C0150 | 29.6 | 8 | 150 | 0.93 |
| 47 | B | T55B476M6R3C0070 | 29.6 | 8 | 70 | 1.36 |
| 47 | B | T55B476M6R3C0060 | 29.6 | 8 | 60 | 1.47 |
| 47 | B | T55B476M6R3C0040 | 29.6 | 8 | 40 | 1.80 |
| 68 | T | T55T686M6R3C0200 | 42.8 | 10 | 200 | 0.72 |
| 68 | T | T55T686M6R3C0150 | 42.8 | 10 | 150 | 0.83 |
| 68 | T | T55T686M6R3C0070 | 42.8 | 10 | 70 | 1.22 |
| 68 | B | T55B686M6R3C0150 | 42.8 | 8 | 150 | 0.93 |
| 68 | B | T55B686M6R3C0070 | 42.8 | 8 | 70 | 1.36 |
| 100 | A | T55A107M6R3C0200 | 63.0 | 10 | 200 | 0.76 |
| 100 | A | T55A107M6R3C0150 | 63.0 | 10 | 150 | 0.88 |
| 100 | A | T55A107M6R3C0100 | 63.0 | 10 | 100 | 1.07 |
| 100 | A | T55A107M6R3C0070 | 63.0 | 10 | 70 | 1.28 |
| 100 | A ⁽¹⁾ | T55A107M6R3C0045 | 63.0 | 10 | 45 | 1.59 |
| 100 | T | T55T107M6R3C0200 | 63.0 | 10 | 200 | 0.72 |
| 100 | T | T55T107M6R3C0070 | 63.0 | 10 | 70 | 1.22 |
| 100 | B | T55B107M6R3C0100 | 63.0 | 8 | 100 | 1.14 |
| 100 | B | T55B107M6R3C0070 | 63.0 | 8 | 70 | 1.36 |
| 100 | B | T55B107M6R3C0055 | 63.0 | 8 | 55 | 1.53 |
| 100 | B | T55B107M6R3C0045 | 63.0 | 8 | 45 | 1.70 |
| 100 | B | T55B107M6R3C0040 | 63.0 | 8 | 40 | 1.80 |
| 100 | B | T55B107M6R3C0035 | 63.0 | 8 | 35 | 1.93 |
| 100 | V | T55V107M6R3C0045 | 63.0 | 10 | 45 | 2.03 |
| 150 | B | T55B157M6R3C0100 | 94.5 | 8 | 100 | 1.14 |
| 150 | B | T55B157M6R3C0070 | 94.5 | 8 | 70 | 1.36 |
| 150 | B | T55B157M6R3C0055 | 94.5 | 8 | 55 | 1.53 |
| 150 | B | T55B157M6R3C0045 | 94.5 | 8 | 45 | 1.70 |
| 150 | B | T55B157M6R3C0040 | 94.5 | 8 | 40 | 1.80 |
| 150 | B | T55B157M6R3C0035 | 94.5 | 8 | 35 | 1.93 |
| 150 | B ⁽¹⁾ | T55B157M6R3C0025 | 94.5 | 8 | 25 | 2.28 |
| 150 | V | T55V157M6R3C0055 | 94.5 | 10 | 55 | 1.84 |
| 150 | V | T55V157M6R3C0045 | 94.5 | 10 | 45 | 2.03 |
| 150 | V | T55V157M6R3C0040 | 94.5 | 10 | 40 | 2.16 |
| 150 | V | T55V157M6R3C0035 | 94.5 | 10 | 35 | 2.31 |
| 150 | V | T55V157M6R3C0025 | 94.5 | 10 | 25 | 2.73 |
| 150 | V | T55V157M6R3C0018 | 94.5 | 10 | 18 | 3.22 |

Notes

- Termination code "C": cases J, P: 100 % tin, case A: 100 % tin or Ni/Pd/Au, cases T, B, V, D: Ni/Pd/Au.
- (1) In development.



| STANDARD RATINGS | | | | | | | |
|--------------------------------------|------------------|------------------|------------------------------------|--------------------------------------|--|--|--|
| CAPACITANCE (μ F) | CASE CODE | PART NUMBER | MAX. DCL AT 25 °C (μ A) | MAX. DF AT 25 °C 120 Hz (%) | MAX. ESR AT + 25 °C 100 kHz (m Ω) | MAX. RIPPLE, AT 45 °C 100 kHz I _{RMS} (A) | |
| 6.3 V_{DC} AT +105 °C | | | | | | | |
| 220 | B | T55B227M6R3C0200 | 138.6 | 8 | 200 | 0.80 | |
| 220 | B | T55B227M6R3C0070 | 138.6 | 8 | 70 | 1.36 | |
| 220 | B | T55B227M6R3C0045 | 138.6 | 8 | 45 | 1.69 | |
| 220 | B | T55B227M6R3C0035 | 138.6 | 8 | 35 | 1.93 | |
| 220 | B | T55B227M6R3C0025 | 138.6 | 8 | 25 | 2.28 | |
| 220 | V | T55V227M6R3C0050 | 138.6 | 10 | 50 | 1.93 | |
| 220 | V | T55V227M6R3C0045 | 138.6 | 10 | 45 | 2.03 | |
| 220 | V | T55V227M6R3C0040 | 138.6 | 10 | 40 | 2.16 | |
| 220 | V | T55V227M6R3C0035 | 138.6 | 10 | 35 | 2.31 | |
| 220 | V | T55V227M6R3C0025 | 138.6 | 10 | 25 | 2.73 | |
| 220 | V | T55V227M6R3C0018 | 138.6 | 10 | 18 | 3.22 | |
| 220 | V | T55V227M6R3C0015 | 138.6 | 10 | 15 | 3.53 | |
| 220 | D | T55D227M6R3C0055 | 138.6 | 10 | 55 | 2.02 | |
| 220 | D | T55D227M6R3C0050 | 138.6 | 10 | 50 | 2.12 | |
| 220 | D | T55D227M6R3C0040 | 138.6 | 10 | 40 | 2.37 | |
| 220 | D | T55D227M6R3C0035 | 138.6 | 10 | 35 | 2.53 | |
| 220 | D | T55D227M6R3C0025 | 138.6 | 10 | 25 | 3.00 | |
| 330 | V | T55V337M6R3C0050 | 207.9 | 10 | 50 | 1.93 | |
| 330 | V | T55V337M6R3C0045 | 207.9 | 10 | 45 | 2.03 | |
| 330 | V | T55V337M6R3C0040 | 207.9 | 10 | 40 | 2.16 | |
| 330 | V | T55V337M6R3C0025 | 207.9 | 10 | 25 | 2.73 | |
| 330 | V | T55V337M6R3C0018 | 207.9 | 10 | 18 | 3.22 | |
| 330 | V | T55V337M6R3C0015 | 207.9 | 10 | 15 | 3.53 | |
| 330 | D | T55D337M6R3C0055 | 207.9 | 10 | 55 | 2.02 | |
| 330 | D | T55D337M6R3C0050 | 207.9 | 10 | 50 | 2.12 | |
| 330 | D | T55D337M6R3C0045 | 207.9 | 10 | 45 | 2.23 | |
| 330 | D | T55D337M6R3C0040 | 207.9 | 10 | 40 | 2.37 | |
| 330 | D | T55D337M6R3C0025 | 207.9 | 10 | 25 | 3.00 | |
| 330 | D | T55D337M6R3C0018 | 207.9 | 10 | 18 | 3.53 | |
| 330 | D | T55D337M6R3C0015 | 207.9 | 10 | 15 | 3.87 | |
| 330 | D | T55D337M6R3C0012 | 207.9 | 10 | 12 | 4.33 | |
| 470 | V ⁽¹⁾ | T55V477M6R3C0055 | 296.1 | 10 | 55 | 1.84 | |
| 470 | V ⁽¹⁾ | T55V477M6R3C0050 | 296.1 | 10 | 50 | 1.93 | |
| 470 | D | T55D477M6R3C0030 | 296.1 | 10 | 30 | 2.73 | |
| 470 | D | T55D477M6R3C0025 | 296.1 | 10 | 25 | 3.00 | |
| 470 | D | T55D477M6R3C0015 | 296.1 | 10 | 15 | 3.87 | |
| 10 V_{DC} AT +105 °C | | | | | | | |
| 3.3 | J | T55J335M010C0500 | 10.0 | 10 | 500 | 0.32 | |
| 3.3 | P | T55P335M010C0500 | 5.0 | 10 | 500 | 0.36 | |
| 4.7 | P | T55P475M010C0500 | 10.0 | 10 | 500 | 0.36 | |
| 4.7 | P | T55P475M010C0200 | 10.0 | 10 | 200 | 0.56 | |
| 4.7 | A | T55A475M010C0500 | 4.7 | 10 | 500 | 0.48 | |
| 4.7 | A | T55A475M010C0300 | 4.7 | 10 | 300 | 0.61 | |
| 4.7 | A | T55A475M010C0200 | 4.7 | 10 | 200 | 0.76 | |
| 6.8 | A | T55A685M010C0500 | 6.8 | 10 | 500 | 0.48 | |
| 6.8 | A | T55A685M010C0300 | 6.8 | 10 | 300 | 0.61 | |
| 6.8 | A | T55A685M010C0200 | 6.8 | 10 | 200 | 0.76 | |
| 10 | A | T55A106M010C0500 | 10.0 | 10 | 500 | 0.48 | |
| 10 | A | T55A106M010C0300 | 10.0 | 10 | 300 | 0.61 | |
| 10 | A | T55A106M010C0200 | 10.0 | 10 | 200 | 0.76 | |
| 15 | A | T55A156M010C0500 | 15.0 | 10 | 500 | 0.48 | |
| 15 | A | T55A156M010C0200 | 15.0 | 10 | 200 | 0.76 | |

Notes

- Termination code "C": cases J, P: 100 % tin, case A: 100 % tin or Ni/Pd/Au, cases T, B, V, D: Ni/Pd/Au.
- (1) In development.



| STANDARD RATINGS | | | | | | | |
|-------------------------------|------------------|------------------|------------------------------------|--------------------------------------|--|--|--|
| CAPACITANCE (μ F) | CASE CODE | PART NUMBER | MAX. DCL AT 25 °C (μ A) | MAX. DF AT 25 °C 120 Hz (%) | MAX. ESR AT + 25 °C 100 kHz (m Ω) | MAX. RIPPLE, AT 45 °C 100 kHz I _{RMS} (A) | |
| 10 V _{DC} AT +105 °C | | | | | | | |
| 22 | A | T55A226M010C0500 | 22.0 | 10 | 500 | 0.48 | |
| 22 | A | T55A226M010C0200 | 22.0 | 10 | 200 | 0.76 | |
| 22 | T | T55T226M010C0200 | 22.0 | 10 | 200 | 0.72 | |
| 22 | T | T55T226M010C0150 | 22.0 | 10 | 150 | 0.84 | |
| 22 | T | T55T226M010C0070 | 22.0 | 10 | 70 | 1.22 | |
| 22 | B | T55B226M010C0300 | 22.0 | 8 | 300 | 0.66 | |
| 22 | B | T55B226M010C0200 | 22.0 | 8 | 200 | 0.81 | |
| 22 | B | T55B226M010C0150 | 22.0 | 8 | 150 | 0.93 | |
| 22 | B | T55B226M010C0070 | 22.0 | 8 | 70 | 1.36 | |
| 33 | A | T55A336M010C0500 | 33.0 | 10 | 500 | 0.48 | |
| 33 | A | T55A336M010C0150 | 33.0 | 10 | 150 | 0.88 | |
| 33 | A | T55A336M010C0070 | 33.0 | 10 | 70 | 1.28 | |
| 33 | A | T55A336M010C0200 | 33.0 | 10 | 200 | 0.76 | |
| 33 | T | T55T336M010C0200 | 33.0 | 10 | 200 | 0.72 | |
| 33 | T | T55T336M010C0150 | 33.0 | 10 | 150 | 0.84 | |
| 33 | T | T55T336M010C0080 | 33.0 | 10 | 80 | 1.14 | |
| 33 | T | T55T336M010C0070 | 33.0 | 10 | 70 | 1.22 | |
| 33 | T ⁽¹⁾ | T55T336M010C0040 | 33.0 | 8 | 40 | 1.62 | |
| 33 | B | T55B336M010C0200 | 33.0 | 8 | 200 | 0.81 | |
| 33 | B | T55B336M010C0150 | 33.0 | 8 | 150 | 0.93 | |
| 33 | B | T55B336M010C0080 | 33.0 | 8 | 80 | 1.27 | |
| 33 | B | T55B336M010C0070 | 33.0 | 8 | 70 | 1.36 | |
| 47 | B | T55B476M010C0150 | 47.0 | 8 | 150 | 0.93 | |
| 47 | B | T55B476M010C0070 | 47.0 | 8 | 70 | 1.36 | |
| 68 | V | T55V686M010C0100 | 68.0 | 10 | 100 | 1.36 | |
| 68 | V | T55V686M010C0060 | 68.0 | 10 | 60 | 1.76 | |
| 100 | V | T55V107M010C0045 | 100.0 | 10 | 45 | 2.03 | |
| 100 | D | T55D107M010C0080 | 100.0 | 10 | 80 | 1.67 | |
| 100 | D | T55D107M010C0055 | 100.0 | 10 | 55 | 2.02 | |
| 100 | D | T55D107M010C0045 | 100.0 | 10 | 45 | 2.23 | |
| 100 | D | T55D107M010C0025 | 100.0 | 10 | 25 | 3.00 | |
| 100 | D | T55D107M010C0018 | 100.0 | 10 | 18 | 3.53 | |
| 150 | V | T55V157M010C0055 | 150.0 | 10 | 55 | 1.84 | |
| 150 | V | T55V157M010C0045 | 150.0 | 10 | 45 | 2.03 | |
| 150 | V | T55V157M010C0040 | 150.0 | 10 | 40 | 2.16 | |
| 150 | V | T55V157M010C0025 | 150.0 | 10 | 25 | 2.73 | |
| 150 | V | T55V157M010C0015 | 150.0 | 10 | 15 | 3.53 | |
| 220 | V | T55V227M010C0050 | 220.0 | 10 | 50 | 1.93 | |
| 220 | V | T55V227M010C0045 | 220.0 | 10 | 45 | 2.03 | |
| 220 | V | T55V227M010C0040 | 220.0 | 10 | 40 | 2.16 | |
| 220 | V | T55V227M010C0025 | 220.0 | 10 | 25 | 2.73 | |
| 220 | V | T55V227M010C0018 | 220.0 | 10 | 18 | 3.22 | |
| 220 | D | T55D227M010C0055 | 220.0 | 10 | 55 | 2.02 | |
| 220 | D | T55D227M010C0050 | 220.0 | 10 | 50 | 2.12 | |
| 220 | D | T55D227M010C0040 | 220.0 | 10 | 40 | 2.37 | |
| 220 | D | T55D227M010C0025 | 220.0 | 10 | 25 | 3.00 | |
| 220 | D | T55D227M010C0018 | 220.0 | 10 | 18 | 3.53 | |
| 330 | D | T55D337M010C0040 | 330.0 | 10 | 40 | 2.37 | |
| 330 | D | T55D337M010C0035 | 330.0 | 10 | 35 | 2.53 | |
| 330 | D | T55D337M010C0025 | 330.0 | 10 | 25 | 3.00 | |
| 330 | D | T55D337M010C0018 | 330.0 | 10 | 18 | 3.53 | |

Notes

- Termination code "C": cases J, P: 100 % tin, case A: 100 % tin or Ni/Pd/Au, cases T, B, V, D: Ni/Pd/Au.
- ⁽¹⁾ In development.



| STANDARD RATINGS | | | | | | |
|---------------------------------------|------------------|------------------|------------------------|-----------------------------|----------------------------------|--|
| CAPACITANCE (μF) | CASE CODE | PART NUMBER | MAX. DCL AT 25 °C (μA) | MAX. DF AT 25 °C 120 Hz (%) | MAX. ESR AT + 25 °C 100 kHz (mΩ) | MAX. RIPPLE, AT 45 °C 100 kHz I _{RMS} (A) |
| 12.5 V_{DC} AT +105 °C | | | | | | |
| 15 | T ⁽¹⁾ | T55T156M12RC0080 | 18.7 | 8 | 80 | 1.14 |
| 16 V_{DC} AT +105 °C | | | | | | |
| 6.8 | B | T55B685M016C0200 | 10.8 | 8 | 200 | 0.80 |
| 10 | B | T55B106M016C0200 | 16.0 | 8 | 200 | 0.80 |
| 10 | B | T55B106M016C0100 | 16.0 | 8 | 100 | 1.14 |
| 15 | B | T55B156M016C0150 | 24.0 | 8 | 150 | 0.93 |
| 15 | B | T55B156M016C0090 | 24.0 | 8 | 90 | 1.20 |
| 22 | B | T55B226M016C0150 | 35.2 | 8 | 150 | 0.93 |
| 22 | B | T55B226M016C0070 | 35.2 | 8 | 70 | 1.36 |
| 33 | V | T55V336M016C0070 | 52.8 | 10 | 70 | 1.63 |
| 47 | V | T55V476M016C0070 | 75.2 | 10 | 70 | 1.63 |
| 47 | V | T55V476M016C0045 | 75.2 | 10 | 45 | 2.03 |
| 100 | V | T55V107M016C0050 | 160.0 | 10 | 50 | 1.93 |
| 20 V_{DC} AT +105 °C | | | | | | |
| 15 | B | T55B156M020C0090 | 30.0 | 8 | 90 | 1.20 |
| 15 | B | T55B156M020C0070 | 30.0 | 8 | 70 | 1.36 |
| 25 V_{DC} AT +105 °C | | | | | | |
| 6.8 | B | T55B685M025C0100 | 17.0 | 8 | 100 | 1.14 |
| 10 | B | T55B106M025C0150 | 25.0 | 8 | 150 | 0.93 |
| 10 | B | T55B106M025C0100 | 25.0 | 8 | 100 | 1.14 |
| 15 | B ⁽¹⁾ | T55B156M025C0100 | 37.5 | 8 | 100 | 1.14 |
| 33 | D ⁽¹⁾ | T55D336M025C0060 | 82.5 | 10 | 60 | 1.93 |
| 100 | D | T55D107M025C0060 | 250.0 | 10 | 60 | 1.93 |
| 35 V_{DC} AT +105 °C | | | | | | |
| 6.8 | B | T55B685M035C0200 | 23.8 | 8 | 200 | 0.81 |
| 22 | D ⁽¹⁾ | T55D226M035C0120 | 77.0 | 10 | 120 | 1.36 |

Notes

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- ⁽¹⁾ In development.

| RECOMMENDED VOLTAGE DERATING GUIDELINES | |
|---|-------------------|
| CAPACITOR VOLTAGE RATING | OPERATING VOLTAGE |
| 2.5 | 2.3 |
| 4.0 | 3.6 |
| 6.3 | 5.7 |
| 10 | 9.0 |
| 12.5 | 11.2 |
| 16 | 12.8 |
| 20 | 16 |
| 25 | 20 |
| 35 | 28 |

| POWER DISSIPATION | |
|-------------------|---|
| CASE CODE | MAXIMUM PERMISSIBLE POWER DISSIPATION (W) AT ≤ +45 °C IN FREE AIR |
| J | 0.050 |
| P | 0.064 |
| A | 0.115 |
| T | 0.105 |
| B | 0.130 |
| V | 0.187 |
| D | 0.225 |



| STANDARD PACKAGING QUANTITY | |
|-----------------------------|-------------------|
| CASE CODE | UNITS PER 7" REEL |
| J | 4000 |
| P | 3000 |
| A | 2000 |
| T | 3000 |
| B | 2000 |
| V | 800 |
| D | 500 |

| PERFORMANCE CHARACTERISTICS | | | | | | | | | | | | | | |
|-----------------------------|---|-----|-----|-----|----|------|----|----|----|----|--|---|--|--|
| ITEM | CONDITION | | | | | | | | | | POST TEST PERFORMANCE | | | |
| Temperature characteristics | Measure the specified characteristics in each stage | | | | | | | | | | | Specified initial value | -55 °C | +105 °C |
| | | | | | | | | | | | Capacitance change | - | -20 % to 0 % | 0 % to 30 % |
| | | | | | | | | | | | Dissipation factor shown in Standard Ratings table or less | 8 to 10 | 14 | - |
| | | | | | | | | | | | Leakage current | Refer to Standard Ratings table | - | Not more than 1 CV or 30 μA which is greater |
| Surge voltage | 105 °C, 1000 successive test cycles in series with a 1 kΩ resistor at the rate of 30 s ON, 30 s OFF; test voltage per table below: | | | | | | | | | | Capacitance change | Within ± 20 % of initial value | | |
| | Rated voltage | 2.5 | 4 | 6.3 | 10 | 12.5 | 16 | 20 | 25 | 35 | Dissipation factor | Within initial limit | | |
| | Surge voltage | 3.2 | 5.2 | 8.2 | 13 | 16 | 20 | 23 | 29 | 40 | Leakage current | Shall not exceed 300 % of initial limit | | |
| Solder heat resistance | Reflow board surface peak temperature: less than 260 °C Time: 5 s max. | | | | | | | | | | Capacitance change | Within ± 20 % of initial value | | |
| | | | | | | | | | | | Dissipation factor | Initial specified value or less | | |
| | | | | | | | | | | | Leakage current | Shall not exceed 300 % of initial specified value | | |
| Moisture resistance no load | Leave at 60 °C and 90 % RH for 500 h | | | | | | | | | | Capacitance change | $V_R \leq 4 \text{ V}$ | Relative to the value before test +50 % to -20 % | |
| | | | | | | | | | | | | $V_R \geq 6.3 \text{ V}$ | Relative to the value before test +40 % to -20 % | |
| | | | | | | | | | | | Dissipation factor | Initial specified value or less | | |
| | | | | | | | | | | | Leakage current | Shall not exceed 300 % of initial specified value | | |
| High temperature load | 105 °C. The rated voltage is applied through a protective resistor of 3 Ω for 1000 h | | | | | | | | | | Capacitance change | Within ± 20 % of initial value | | |
| | | | | | | | | | | | Dissipation factor | Initial specified value or less | | |
| | | | | | | | | | | | Leakage current | Shall not exceed 300 % of initial specified value | | |
| Thermal shock | Leave at -55 °C, normal temperature, 105 °C, and normal temperature for 30 min., 15 min. 30 min., and 15 min. Repeat this operation 5 times running. | | | | | | | | | | Capacitance change | Within ± 20 % of initial value or less | | |
| | | | | | | | | | | | Dissipation factor | Initial specified value or less | | |
| | | | | | | | | | | | Leakage current | Shall not exceed 300 % of initial specified value | | |
| Failure rate | 105 °C. The rated voltage is applied through a protective resistor of 1 Ω/V. | | | | | | | | | | 1 % / 1000 h | | | |

Note

- Test conditions per JIS C5101-1



Guide for Tantalum Solid Electrolyte Chip Capacitors with Polymer Cathode

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum/tantalum oxide/manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve" metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance/volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance/volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

| COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS | |
|--|-----------------------------------|
| DIELECTRIC | ϵ DIELECTRIC CONSTANT |
| Air or vacuum | 1.0 |
| Paper | 2.0 to 6.0 |
| Plastic | 2.1 to 6.0 |
| Mineral oil | 2.2 to 2.3 |
| Silicone oil | 2.7 to 2.8 |
| Quartz | 3.8 to 4.4 |
| Glass | 4.8 to 8.0 |
| Porcelain | 5.1 to 5.9 |
| Mica | 5.4 to 8.7 |
| Aluminum oxide | 8.4 |
| Tantalum pentoxide | 26 |
| Ceramic | 12 to 400K |

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{\epsilon A}{t}$$

where

C = capacitance

ϵ = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.

SOLID ELECTROLYTE POLYMER TANTALUM CAPACITORS

Solid electrolyte polymer capacitors utilize sintered tantalum pellets as anodes. Tantalum pentoxide dielectric layer is formed on the entire surface of anode, which is further impregnated with highly conductive polymer as cathode system.

The conductive polymer layer is then coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the capacitor element and the outer termination (lead frame or other).

Molded chip polymer tantalum capacitor encases the element in plastic resins, such as epoxy materials. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for variety of applications in electronic devices. Usage of conductive polymer cathode system provides very low equivalent series resistance (ESR), which makes the capacitors particularly suitable for high frequency applications.

TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T55



TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T58



TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T52



TANTALUM CAPACITOR WITH POLYMER CATHODE TYPE T54 / T59



| SOLID TANTALUM CAPACITORS - MOLDED CASE | |
|---|--|
| SERIES | T55 |
| PRODUCT IMAGE |  |
| TYPE | VPolyTan™, molded case, high performance polymer |
| FEATURES | High performance |
| TEMPERATURE RANGE | -55 °C to +105 °C |
| CAPACITANCE RANGE | 3.3 µF to 680 µF |
| VOLTAGE RANGE | 2.5 V to 35 V |
| CAPACITANCE TOLERANCE | ± 20 % |
| LEAKAGE CURRENT | 0.1 CV |
| DISSIPATION FACTOR | 8 % to 10 % |
| ESR | 15 mΩ to 500 mΩ |
| CASE SIZES | J, P, A, T, B, V, D |
| TERMINATION FINISH | Cases J, P: 100 % tin Case A: 100 % tin or Ni/Pd/Au Cases T, B, V, D: Ni/Pd/Au |

| SOLID TANTALUM CAPACITORS - LEADFRAMELESS MOLDED CASE | | | | |
|---|---|---|---|--|
| SERIES | T52 | T58 | T59 | T54 |
| PRODUCT IMAGE |  |  |  |  |
| TYPE | vPolyTan™ solid tantalum surface mount chip capacitors, leadframeless molded polymer type | vPolyTan™ solid tantalum surface mount chip capacitors, leadframeless molded polymer type | vPolyTan™ solid tantalum surface mount chip capacitors, leadframeless molded polymer type | vPolyTan™ solid tantalum surface mount chip capacitors, leadframeless molded polymer type, commercial off-the-shelf (COTS) |
| FEATURES | Low profile | Small case size | Multianode | Hi-rel COTS, multianode |
| TEMPERATURE RANGE | -55 °C to +105 °C (above 85 °C, voltage derating is required) | -55 °C to +105 °C (above 85 °C, voltage derating is required) | -55 °C to +105 °C (above 85 °C, voltage derating is required) | -55 °C to +105 °C (above 85 °C, voltage derating is required) |
| CAPACITANCE RANGE | 330 µF to 2200 µF | 1 µF to 330 µF | 10 µF to 470 µF | 10 µF to 470 µF |
| VOLTAGE RANGE | 6.3 V to 16 V | 4 V to 35 V | 16 V to 75 V | 16 V to 75 V |
| CAPACITANCE TOLERANCE | ± 10 %, ± 20 % | ± 20 % | ± 10 %, ± 20 % | ± 20 % |
| LEAKAGE CURRENT | 0.1 CV | | | |
| DISSIPATION FACTOR | 10 % | 8 % to 14 % | 10 % | 10 % |
| ESR | 25 mΩ to 55 mΩ | 90 mΩ to 500 mΩ | 25 mΩ to 100 mΩ | 25 mΩ to 100 mΩ |
| CASE SIZES | E1, M1 | MM, M0, W0, W9, A0, AA, B0, BB | EE | EE |
| TERMINATION | 100 % tin | | | 100 % tin / lead |

MOLDED CAPACITORS, T55 TYPE

PLASTIC TAPE AND REEL PACKAGING DIMENSIONS in millimeters



| TAPE WIDTH | 8 | 12 |
|-------------|-----|-------|
| A + 0 / - 3 | | Ø 180 |
| B + 1 / 0 | | Ø 60 |
| C ± 0.2 | | Ø 13 |
| D ± 0.5 | | Ø 21 |
| E ± 0.5 | | 2.0 |
| W ± 0.3 | 9.0 | 13.0 |

Note

- A reel diameter of 330 mm is also applicable.

PLASTIC TAPE SIZE DIMENSIONS in millimeters



| CASE CODE | A ± 0.2 | B ± 0.2 | W ± 0.3 | F ± 0.1 | E ± 0.1 | P ₁ ± 0.1 | t _{max.} |
|-----------|---------|---------|---------|---------|---------|----------------------|-------------------|
| J | 1.0 | 1.8 | 8.0 | 3.5 | 1.75 | 4.0 | 1.3 |
| P | 1.4 | 2.2 | 8.0 | 3.5 | 1.75 | 4.0 | 1.6 |
| A | 1.9 | 3.5 | 8.0 | 3.5 | 1.75 | 4.0 | 2.5 |
| T | 3.1 | 3.8 | 8.0 | 3.5 | 1.75 | 4.0 | 1.7 |
| B | 3.1 | 3.8 | 8.0 | 3.5 | 1.75 | 4.0 | 2.5 |
| V | 4.8 | 7.7 | 12.0 | 5.5 | 1.75 | 8.0 | 2.6 |
| D | 4.8 | 7.7 | 12.0 | 5.5 | 1.75 | 8.0 | 3.4 |

Note

- A reel diameter of 330 mm is also applicable.

LEADFRAMELESS MOLDED CAPACITORS, ALL TYPES



| CARRIER TAPE DIMENSIONS in inches [millimeters] | | | | | | | |
|---|-----------|--------------------------------------|-----------------------|-------------------------------|-----------------------|-----------------------------|--|
| CASE CODE | TAPE SIZE | B ₁ (MAX.) ⁽¹⁾ | D ₁ (MIN.) | F | K ₀ (MAX.) | P ₁ | W |
| E1 | TBD | | | | | | |
| MM ⁽²⁾ | 8 mm | 0.075 [1.91] | 0.02 [0.5] | 0.138 [3.5] | 0.043 [1.10] | 0.157 [4.0] | 0.315 [8.0] |
| M0 | TBD | | | | | | |
| M1 | 12 mm | 0.32 [8.2] | 0.059 [1.5] | 0.217 ± 0.002 [5.5 ± 0.05] | 0.094 [2.39] | 0.315 ± 0.04 [8.0 ± 1.0] | 0.472 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.10] |
| W9 | 8 mm | 0.126 [3.20] | 0.030 [0.75] | 0.138 [3.5] | 0.045 [1.15] | 0.157 [4.0] | 0.315 [8.0] |
| W0 | 8 mm | 0.126 [3.20] | 0.030 [0.75] | 0.138 [3.5] | 0.045 [1.15] | 0.157 [4.0] | 0.315 [8.0] |
| A0 | 8 mm | - | 0.02 [0.5] | 0.138 [3.5] | 0.049 [1.25] | 0.157 [4.0] | 0.315 [8.0] |
| AA | 8 mm | 0.154 [3.90] | 0.039 [1.0] | 0.138 [3.5] | 0.079 [2.00] | 0.157 [4.0] | 0.315 [8.0] |
| B0 | 12 mm | 0.181 [4.61] | 0.059 [1.5] | 0.217 [5.5] | 0.049 [1.25] | 0.157 [4.0] | 0.315 [8.0] |
| BB | 8 mm | 0.157 [4.0] | 0.039 [1.0] | 0.138 [3.5] | 0.087 [2.22] | 0.157 [4.0] | 0.315 [8.0] |
| EE | 12 mm | 0.32 [8.2] | 0.059 [1.5] | 0.217 ± 0.002 [5.5 ± 0.05] | 0.175 [4.44] | 0.315 ± 0.04 [8.0 ± 1.0] | 0.472 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.10] |

Notes

- ⁽¹⁾ For reference only.
- ⁽²⁾ Standard packaging of MM case is with paper tape. Plastic tape is available per request.

| PAPER TAPE AND REEL PACKAGING DIMENSIONS in inches [millimeters] | | | | | | | | | | | |
|---|-----------|--------------------------------|-------------------------------|-----------------------------|------------------------------|------------------------------|-------------------------------|-------------------------------|--------------------------------|------------------------------|--------------------------------|
| <p>The diagram illustrates the dimensions of a paper tape and its reel packaging. It shows a top cover tape and a bottom cover tape. The cavity center lines are indicated, along with the anode size and the cavity size. Dimensions A₀, B₀, D₀, P₀, P₁, P₂, E, F, W, and T are labeled. A note indicates a cumulative tolerance of ± 0.2 mm on the tape for 10 pitches. The user feed direction is shown as an arrow pointing to the right.</p> | | | | | | | | | | | |
| CASE SIZE | TAPE SIZE | A ₀ | B ₀ | D ₀ | P ₀ | P ₁ | P ₂ | E | F | W | T |
| MM | 8 mm | 0.041 ± 0.002 [1.05 ± 0.05] | 0.071 ± 0.002 [1.8 ± 0.05] | 0.06 ± 0.004 [1.5 ± 0.1] | 0.157 ± 0.004 [4.0 ± 0.1] | 0.157 ± 0.004 [4.0 ± 0.1] | 0.079 ± 0.002 [2.0 ± 0.05] | 0.069 ± 0.004 [1.75 ± 0.1] | 0.0138 ± 0.002 [3.5 ± 0.05] | 0.315 ± 0.008 [8.0 ± 0.2] | 0.037 ± 0.002 [0.95 ± 0.05] |

Note

- ⁽¹⁾ A₀, B₀ are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A₀, B₀) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°.

PACKING AND STORAGE

Polymer capacitors meet moisture sensitivity level rating (MSL) of 3 as specified in IPC/JEDEC® J-STD-020 and are dry packaged in moisture barrier bags (MBB) per J-STD-033. Level 3 specifies a floor life (out of bag) of 168 hours at 30 °C maximum and 60 % relative humidity (RH). Unused capacitors should be re-sealed in the MBB with fresh desiccant. A moisture strip (humidity indicator card) is included in the bag to assure dryness. To remove excess moisture, capacitors can be dried at 40 °C (standard “dry box” conditions).

For detailed recommendations please refer to J-STD-033.



| PEAK PACKAGE BODY TEMPERATURE (T_p) MAXIMUM | | | |
|---|--------------------------------|--|-------------------------|
| TYPE | CASE CODE | PEAK PACKAGE BODY TEMPERATURE (T_p) MAX. | |
| | | SnPb EUTECTIC ASSEMBLY | LEAD (Pb)-FREE ASSEMBLY |
| T55 | J, P, A, T, B, V, D | n/a | 260 °C |
| T52 | E1, M1 | | 260 °C |
| T58 | MM, M0, W9, W0, A0, AA, B0, BB | | 260 °C |
| T59 | EE | | 250 °C |
| T54 | EE | | 220 °C |

Notes

- T52, T55, and T58 capacitors are process sensitive. PSL classification to JEDEC J-STD-075: R4G
- T54 capacitors with 100 % tin termination and T59 capacitors are process sensitive. PSL classification to JEDEC J-STD-075: R6G

MOLDED CAPACITORS, T55 TYPE

| PAD DIMENSIONS in millimeters | | | | | | |
|-------------------------------|----------------|------|----------------|----------|----------|----------|
| | | | | | | |
| CASE / DIMENSIONS | CAPACITOR SIZE | | PAD DIMENSIONS | | | |
| | L | W | G (max.) | Z (min.) | X (min.) | Y (Ref.) |
| J | 1.6 | 0.8 | 0.7 | 2.5 | 1.0 | 0.9 |
| P | 2.0 | 1.25 | 0.5 | 2.6 | 1.2 | 1.05 |
| A | 3.2 | 1.6 | 1.1 | 3.8 | 1.5 | 1.35 |
| T / B | 3.5 | 2.8 | 1.4 | 4.1 | 2.7 | 1.35 |
| V / D | 7.3 | 4.3 | 4.1 | 8.2 | 2.9 | 2.05 |

LEADFRAMELESS MOLDED CAPACITORS, ALL TYPES

| PAD DIMENSIONS in inches [millimeters] | | | | | |
|--|-----------|--------------|--------------|--------------|--------------|
| | | | | | |
| TYPE | CASE CODE | A (MIN.) | B (NOM.) | C (NOM.) | D (NOM.) |
| T52 | E1 | 0.209 [5.30] | 0.098 [2.5] | 0.169 [4.3] | 0.366 [9.3] |
| | M1 | 0.276 [7.00] | 0.098 [2.5] | 0.169 [4.3] | 0.366 [9.3] |
| T58 | MM / M0 | 0.039 [1.00] | 0.028 [0.70] | 0.024 [0.60] | 0.080 [2.00] |
| | W0 / W9 | 0.059 [1.50] | 0.031 [0.80] | 0.039 [1.00] | 0.102 [2.60] |
| | AA / A0 | 0.071 [1.80] | 0.067 [1.70] | 0.053 [1.35] | 0.187 [4.75] |
| | BB / B0 | 0.118 [3.00] | 0.071 [1.80] | 0.065 [1.65] | 0.207 [5.25] |
| T59 / T54 | EE | 0.209 [5.30] | 0.098 [2.5] | 0.169 [4.3] | 0.366 [9.3] |

GUIDE TO APPLICATION

- AC Ripple Current:** the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = power dissipation in W at +45 °C as given in the tables in the product datasheets.

R_{ESR} = the capacitor equivalent series resistance at the specified frequency.

- AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = Z \sqrt{\frac{P}{R_{ESR}}}$$

or, from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

where,

P = power dissipation in W at +45 °C as given in the tables in the product datasheets.

R_{ESR} = The capacitor equivalent series resistance at the specified frequency.

Z = The capacitor impedance at the specified frequency.

- The tantalum capacitors must be used in such a condition that the sum of the working voltage and ripple voltage peak values does not exceed the rated voltage as shown in figure below.



- Temperature Derating:** power dissipation is affected by the heat sinking capability of the mounting surface. If these capacitors are to be operated at temperatures above +45 °C, the permissible ripple current (or voltage) shall be calculated using the derating coefficient as shown in the table below:

| MAXIMUM RIPPLE CURRENT TEMPERATURE DERATING FACTOR | |
|--|-----|
| ≤ 45 °C | 1.0 |
| 55 °C | 0.8 |
| 85 °C | 0.6 |
| 105 °C | 0.4 |

- Reverse Voltage:** these capacitors are capable of withstanding peak voltages in the reverse direction equal to 10 % of the DC rating at +25 °C, 5 % of the DC rating at +25 °C, 5 % of the DC rating at +85 °C, and 1 % of the DC rating at +105 °C.

- Mounting Precautions:**

- Limit Pressure on Capacitor Installation with Mouter:** pressure must not exceed 4.9 N with a tool end diameter of 1.5 mm when applied to the capacitors using an absorber, centering tweezers, or similar (maximum permitted pressurization time: 5 s). An excessively low absorber setting position would result in not only the application of undue force to the capacitors but capacitor and other component scattering, circuit board wiring breakage, and / or cracking as well, particularly when the capacitors are mounted together with other chips having a height of 1 mm or less.

- Flux Selection**

- 5.2.1 Select a flux that contains a minimum of chlorine and amine.

- 5.2.2 After flux use, the chlorine and amine in the flux remain must be removed.

- Cleaning After Mounting:** the following solvents are usable when cleaning the capacitors after mounting. Never use a highly active solvent.

- Halogen organic solvent (HCFC225, etc.)
- Alcoholic solvent (IPA, ethanol, etc.)
- Petroleum solvent, alkali saponifying agent, water, etc.

Circuit board cleaning must be conducted at a temperature of not higher than 50 °C and for an immersion time of not longer than 30 minutes. When an ultrasonic cleaning method is used, cleaning must be conducted at a frequency of 48 kHz or lower, at an vibrator output of 0.02 W/cm³, at a temperature of not higher than 40 °C, and for a time of 5 minutes or shorter.

Notes

- Care must be exercised in cleaning process so that the mounted capacitor will not come into contact with any cleaned object or the like or will not get rubbed by a stiff brush or similar. If such precautions are not taken particularly when the ultrasonic cleaning method is employed, terminal breakage may occur.
- When performing ultrasonic cleaning under conditions other than stated above, conduct adequate advance checkout.



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